

3.3-V CAN TRANSCEIVERS

FEATURES

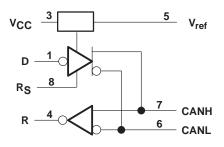
- Controlled Baseline
 - One Assembly/Test Site, One Fabrication Site
- Extended Temperature Performance of -55°C to 125°C
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product-Change Notification
- Qualification Pedigree†
- Operates With a 3.3-V Supply
- Low Power Replacement for the PCA82C250 Footprint
- Bus/Pin ESD Protection Exceeds 15-kV HBM
- Controlled Driver Output Transition Times for Improved Signal Quality on the SN65HVD230M
- Unpowered Node Does Not Disturb the Bus
- Compatible With the Requirements of the ISO 11898 Standard

- Low-Current SN65HVD230M Standby Mode 370 μA Typical
- Designed for Signaling Rates[‡] Up To 1 Megabit/Second (Mbps)
- Thermal Shutdown Protection
- Open-Circuit Fail-Safe Design

† Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

logic diagram (positive logic)

SN65HVD230M Logic Diagram (Positive Logic)





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

[‡] The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).



DESCRIPTION

The SN65HVD230M controller area network (CAN) transceiver is designed for use with the Texas Instruments TMS320Lx240x 3.3-V DSPs with CAN controllers, or with equivalent devices. They are intended for use in applications employing the CAN serial communication physical layer in accordance with the ISO 11898 standard. Each CAN transceiver is designed to provide differential transmit capability to the bus and differential receive capability to a CAN controller at speeds up to 1 Mbps.

Designed for operation in especially-harsh environments, these devices feature cross-wire protection, loss-of-ground and overvoltage protection, overtemperature protection, as well as wide common-mode range.

The transceiver interfaces the single-ended CAN controller with the differential CAN bus found in industrial, building automation, and automotive applications. It operates over a -2-V to 7-V common-mode range on the bus and it can withstand common-mode transients of ± 25 V.

On the SN65HVD230M, R_S (pin 8) provides three different modes of operation: high-speed, slope control, and low-power modes. The high-speed mode of operation is selected by connecting pin 8 to ground, allowing the transmitter output transistors to switch on and off as fast as possible with no limitation on the rise and fall slopes. The rise and fall slopes can be adjusted by connecting a resistor to ground at pin 8, since the slope is proportional to the pin's output current. This slope control is implemented with external resistor values of 10 k Ω , to achieve a 15-V/ μ s slew rate, to 100 k Ω , to achieve a 2-V/ μ s slew rate.

The circuit of the SN65HVD230M enters a low-current standby mode during which the driver is switched off and the receiver remains active if a high logic level is applied to R_S (pin 8). The DSP controller reverses this low-current standby mode when a dominant state (bus differential voltage > 900 mV typical) occurs on the bus.

The V_{ref} (pin 5 on the SN65HVD230M) is available as a $V_{CC}/2$ voltage reference.

AVAILABLE OPTIONS

FUNCTION LOW NUMBER POWER MODE		INTEGRATED SLOPE CONTROL	Vref PIN	
'230	370-μA standby mode	Yes	Yes	

PART NUMBER Q100		Q100	T _A	MARKED AS		
	SN65HVD230MDREP	No	-55°C to 125°C	HV230M		



Function Tables

DRIVER (SN65HVD230M)

INDUT	_	OUTI	PUTS	DUO OTATE	
INPUT D	R _S	CANH	CANL	BUS STATE	
L	V _(Rs) < 1.2 V	Н	L	Dominant	
Н		Z	Z	Recessive	
Open	X	Z	Z	Recessive	
X	$V_{(Rs)} > 0.75 V_{CC}$	Z	Z	Recessive	

H = high level; L = low level; X = irrelevant; ? = indeterminate

RECEIVER (SN65HVD230M)

DIFFERENTIAL INPUTS	RS	OUTPUT R
V _{ID} ≥ 0.9 V	Х	L
0.5 V < V _{ID} < 0.9 V	Х	?
V _{ID} ≤ 0.5 V	Х	Н
Open	Х	Н

H = high level; L = low level; X = irrelevant; ? = indeterminate

TRANSCEIVER MODES (SN65HVD230M)

V _(Rs)	OPERATING MODE
V _(RS) > 0.75 V _{CC}	Standby
10 k Ω to 100 k Ω to ground	Slope control
V _(RS) < 1 V	High speed (no slope control)

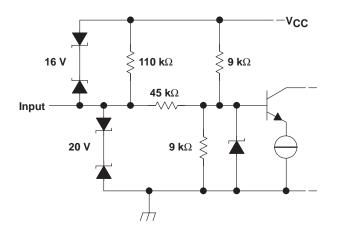
Terminal Functions

	SN65HVD230M				
TERMIN	AL	DESCRIPTION			
NAME	NO.	DESCRIPTION			
CANL	6	Low bus output			
CANH	7	High bus output			
D	1	Driver input			
GND	2	Ground			
R	4	Receiver output			
RS	8	Standby/slope control			
VCC	3	Supply voltage			
V _{ref}	5	Reference output			

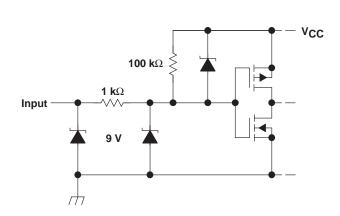


equivalent input and output schematic diagrams

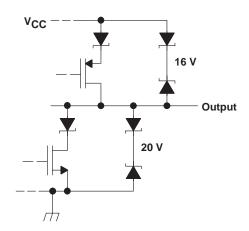
CANH and CANL Inputs



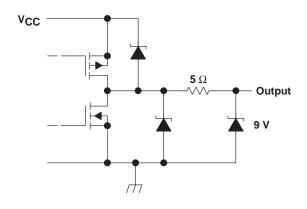
D Input



CANH and CANL Outputs



R Output



absolute maximum ratings over operating free-air temperature (see Note 1) (unless otherwise noted)†

Supply voltage range, V _{CC}	–7 V to 16 V
Voltage input range, transient pulse, CANH and CANL, throu	, ,
Input voltage range, V _I (D or R)	–0.5 V to V _{CC} + 0.5 V
Electrostatic discharge: Human body model (see Note 2)	CANH, CANL and GND 15 kV
	All pins 2.5 kV
Charged-device model (see Note 3)	All pins 4 kV
Continuous total power dissipation	See Dissipation Rating table
Storage temperature range, T _{sta}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 secon	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

- 2. Tested in accordance with JEDEC Standard 22, Test Method A114-A.
- 3. Tested in accordance with JEDEC Standard 22, Test Method C101.
- 4. Long-term high-temperature storage and/or extended use at maximum recommended operating conditions may result in a reduction of overall device life. See http://www.ti.com/ep_quality for additional information on enhanced plastic packaging.

DISSIPATION RATING TABLE

	PACKAGE	$T_{\mbox{\scriptsize A}} \leq 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	DERATING FACTOR [‡] ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
ı	D	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW

[‡]This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

recommended operating conditions

PARAMETER		MIN	NOM MA	X UNIT
Supply voltage, V _{CC}		3	3.	6 V
Voltage at any bus terminal (common mode) V _{IC}		-2 \$		7 V
Voltage at any bus terminal (separately) V _I		-2.5	7.	5 V
High-level input voltage, VIH	D, R	2		V
Low-level input voltage, V _{IL}	D, R		0.	8 V
Differential input voltage, V _{ID} (see Figure 5)		-6		6 V
V(RS)		0	٧c	C V
V _(RS) for standby or sleep		0.75 V _{CC}	٧c	o V
Rs wave-shaping resistance		0	10	0 kΩ
IP-de lavel code of comment I	Driver	-40		
	-8		mA	
Level and autorit annual 1	Driver		4	
Low-level output current, I _{OL}	Receiver			8 mA
Operating free-air temperature, TA		-55	12	5 °C

[§] The algebraic convention, in which the least positive (most negative) limit is designated as minimum is used in this data sheet.



driver electrical characteristics over recommended operating conditions (unless otherwise noted)

	PARA	METER		TE	ST CONDITION	IS	MIN	TYP [†]	MAX	UNIT
.,				V _I = 0 V, See Figure 1 and Figure 3		CANH	2.45		VCC	
	Bus output	Dominant		See Figure 1	and Figure 3	CANL	0.5		1.25	.,
voltage	Danasius		V _I = 3 V,	and Figure 3	CANH		2.3		V	
VOL	V _{OL}	Recessive		See Figure 1	and Figure 3	CANL		2.3		
.,		Danisant		$V_I = 0 V$,	See Figure 1		1.5	2	3	.,
VOD(D)	VOD(D) Differential output		Dominant		V _I = 0 V, See Figure 2		1.2	2	3	V
.,	voltage			V _I = 3 V, See Figure 1		-120	0	12	mV	
V _{OD} (R)		Recessive		V _I = 3 V,	No load		-0.5	-0.2	0.05	V
lн	High-level input cu	rrent		V _I = 2 V		-30			μΑ	
I _I L	Low-level input cur	rent		V _I = 0.8 V			-30			μΑ
	0			VCANH = -2	2 V		-250		250	•
los	Short-circuit output	current		V _{CANL} = 7 V		-250		250	mA	
Co	C ₀ Output capacitance		See receiver							
	_	Standby	SN65HVD230M	$V_{(RS)} = V_{CO}$				370	600	μΑ
ICC	Supply current	All devices	Dominant	$V_I = 0 V$,	No load	Dominant		10	17	mA
		All devices	Recessive	$V_I = V_{CC}$,	No load	Recessive		10	17	IIIA

[†] All typical values are at 25°C and with a 3.3-V supply.

driver switching characteristics at T_A = 25°C (unless otherwise noted)

	PARAMETER	TEST CONDITION	ONS	MIN	TYP	MAX	UNIT
		V(RS) = 0 V			35	85	
tPLH	Propagation delay time, low-to-high-level output	Rs with 10 k Ω to ground			70	190	ns
		R_S with 100 $k\Omega$ to ground		35 8 70 19 500 87 70 13 130 20 870 120 35 60 370 25 50 10 40 55 8 75 120 16 80 125 15	870		
		V(RS) = 0 V			70	130	
t _{PHL}	Propagation delay time, high-to-low-level output	Rs with 10 k Ω to ground]		130	205	ns
		Rs with 100 k Ω to ground]		1200		
	sk(p) Pulse skew (tp(HL) - tp(LH))	V(RS) = 0 V]		35		
tsk(p)		Rs with 10 k Ω to ground	C _L = 50 pF, See Figure 4		60		ns
tsk(p)		R_S with 100 $k\Omega$ to ground	Occ rigare 4		370		
t _r	Differential output signal rise time]	25	50	100	ns
t _f	Differential output signal fall time	V(RS) = 0 V		40	55	80	ns
t _r	Differential output signal rise time	5 W 404 0 4]	75	120	160	ns
t _f	Differential output signal fall time	R _S with 10 k Ω to ground		80	125	150	ns
t _r	Differential output signal rise time	B *1 400 LO /]	350	800	1200	ns
t _f	Differential output signal fall time	R _S with 100 kΩ to ground		600	825	1200	ns

receiver electrical characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIO	NS	MIN	TYP [†]	MAX	UNIT
V _{IT+}	Positive-going input threshold voltage	0 711 /			750	900	mV
VIT-	Negative-going input threshold voltage	See Table 1		500	650		.,
V _{hys}	Hysteresis voltage (V _{IT+ -} V _{IT-})				100		mV
VOH	High-level output voltage	$-6 \text{ V} \le \text{V}_{\text{ID}} \le 500 \text{ mV}, \text{ I}_{\text{O}} = -8 \text{ mA}, \text{ See Figure 5}$		2.4			V
VOL	Low-level output voltage	$900 \text{ mV} \le \text{V}_{1D} \le 6 \text{ V}, \text{I}_{O} = 8 \text{ mA}, \text{Se}$	A, See Figure 5			0.4	
	Bus input current	V _{IH} = 7 V	Other input at 0 V, D = 3 V	100		250	
VIT- I Vhys I VOH I VOL I Ci C Cdiff I Rdiff I		V _{IH} = 7 V, V _{CC} = 0 V		100		350	μА
		V _{IH} = −2 V		-200		-30	
		$V_{IH} = -2 \text{ V}, \text{ V}_{CC} = 0 \text{ V}$]	-100		-20	μΑ
Ci	CANH, CANL input capacitance	Pin-to-ground, V _I = 0.4 sin(4E6πt) + 0.5 V	V _(D) = 3 V,		32		pF
C _{diff}	Differential input capacitance	Pin-to-pin, V _I = 0.4 sin(4E6πt) + 0.5 V	V _(D) = 3 V,		16		pF
R _{diff}	Differential input resistance	Pin-to-pin, $V_{(D)} = 3 V$		40	70	100	kΩ
RT	CANH, CANL input resistance			20	35	50	kΩ
ICC	Supply current	See driver					

[†] All typical values are at 25°C and with a 3.3-V supply.

receiver switching characteristics at T_A = 25°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
tPLH	Propagation delay time, low-to-high-level output			35	55	ns	
tPHL	Propagation delay time, high-to-low-level output	See Figure 6		35	55	ns	
tsk(p)	Pulse skew (tp(HL) - tp(LH))				10	ns	
t _r	Output signal rise time	0		1.5		ns	
tf	Output signal fall time	See Figure 6		1.5		ns	
t _(loop)	Total loop delay, driver input to receiver output	V(RS) = 0 V			70	135	
t(loop)	Total loop delay, driver input to receiver output	R_S with 10 $k\Omega$ to ground			105	175	ns
t(loop)	Total loop delay, driver input to receiver output	Rs with 100 k Ω to ground			535	920	



device control-pin characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t(WAKE)	SN65HVD230M wake-up time from standby mode with $\ensuremath{\text{R}_{\text{\cite{S}}}}$	See Figure 8		0.55	1.5	μS
.,	Defended automitient	$-5 \mu\text{A} < I_{(Vref)} < 5 \mu\text{A}$	0.45 V _{CC}		0.55 V _{CC}	.,
V _{ref} Reference output voltage		$-50 \mu\text{A} < I_{(Vref)} < 50 \mu\text{A}$	0.4 V _{CC}		0.6 V _{CC}	V
I _(RS)	Input current for high-speed	V _(RS) < 1 V	-450		0	μΑ

[†] All typical values are at 25°C and with a 3.3 V supply.

PARAMETER MEASUREMENT INFORMATION

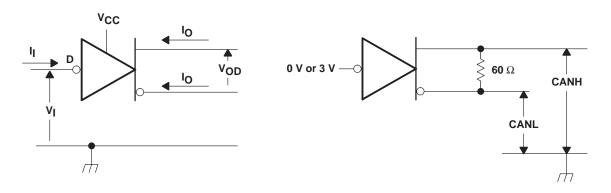


Figure 1. Driver Voltage and Current Definitions

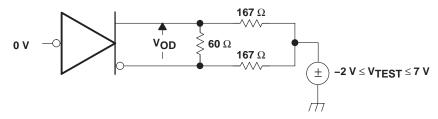


Figure 2. Driver VOD

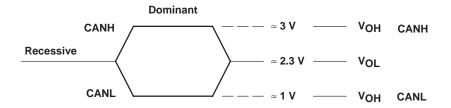
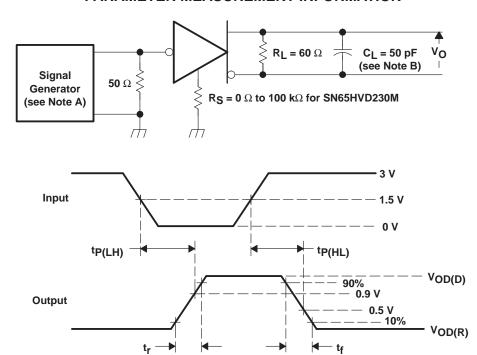


Figure 3. Driver Output Voltage Definitions

PARAMETER MEASUREMENT INFORMATION



NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 500 kHz, 50% duty cycle, $t_f \leq$ 6 ns, $t_f \leq$ 7 ns, $t_f \leq$ 8 ns, $t_f \leq$ 8 ns, $t_f \leq$ 8 ns, $t_f \leq$ 9 ns, $t_$

B. C_L includes probe and jig capacitance.

Figure 4. Driver Test Circuit and Voltage Waveforms

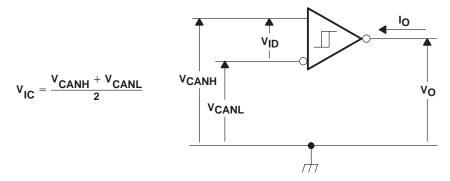
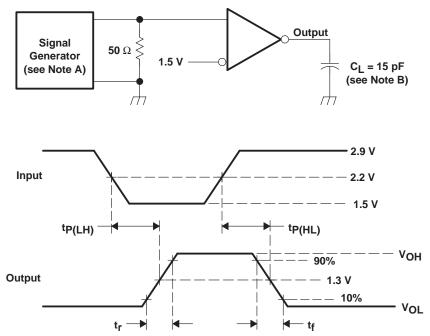


Figure 5. Receiver Voltage and Current Definitions

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 500 kHz, 50% duty cycle, $t_{\Gamma} \leq$ 6 ns, $t_{f} \leq$ 7 ns, $t_{f} \leq$ 8 ns, $t_{f} \leq$ 8 ns, $t_{f} \leq$ 9 ns,
 - B. C_I includes probe and jig capacitance.

Figure 6. Receiver Test Circuit and Voltage Waveforms

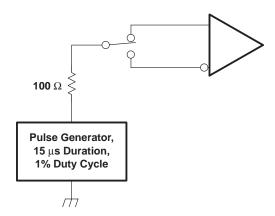
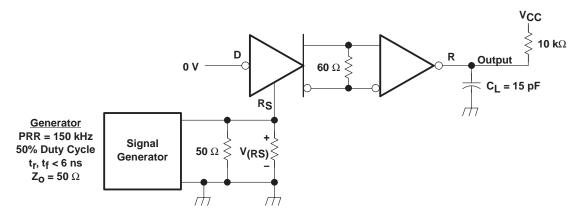


Figure 7. Overvoltage Protection

PARAMETER MEASUREMENT INFORMATION

Table 1. Receiver Characteristics Over Common Mode With V(RS) at 1.2 V

V _{IC}	V _{ID}	VCANH	VCANL	R OU	TPUT	
–2 V	900 mV	900 mV		L		
7 V	900 mV	8.45 V	6.55 V	L	V	
1 V	6 V	4 V	–2 V	L	VOL	
4 V	4 V 6 V		1 V	L		
–2 V	500 mV	–1.75 V	–2.25 V	Н		
7 V	500 mV	7.25 V	6.75 V	Н		
1 V	-6 V	–2 V	4 V	Н	Vон	
4 V	4 V -6 V		7 V	Н		
Х	Х	Open	Open	Н		



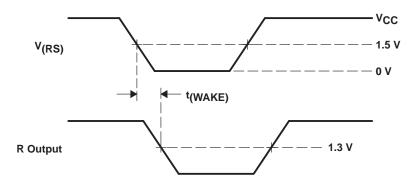
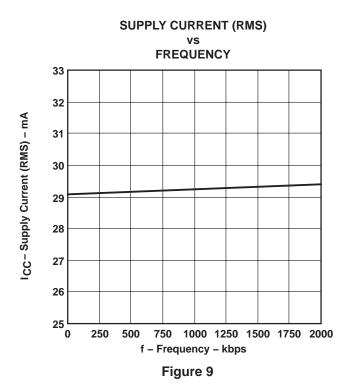
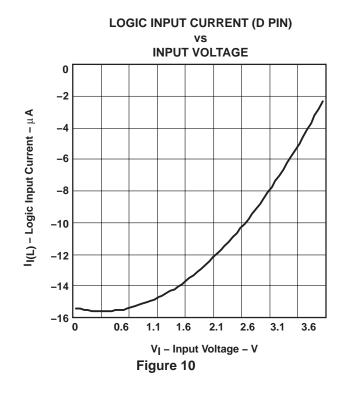
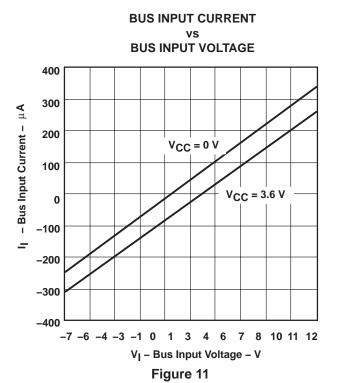
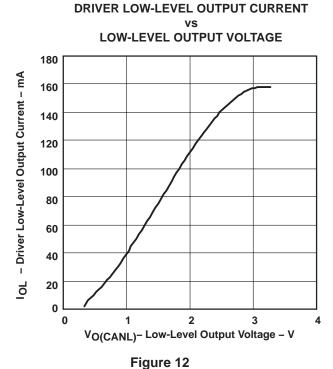


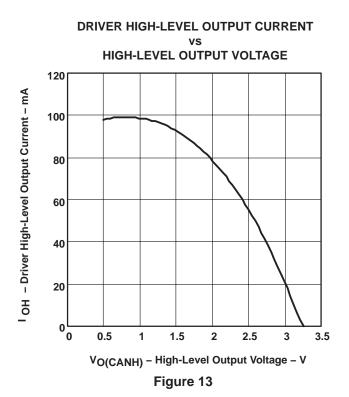
Figure 8. t_(WAKE) Test Circuit and Voltage Waveforms

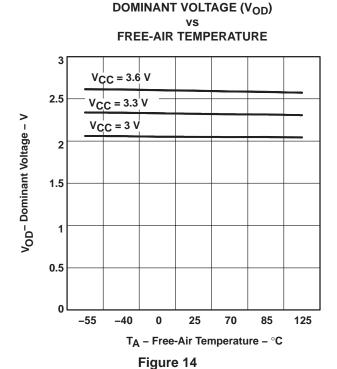




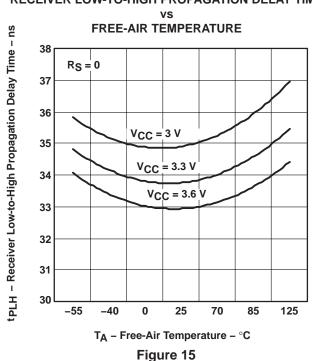




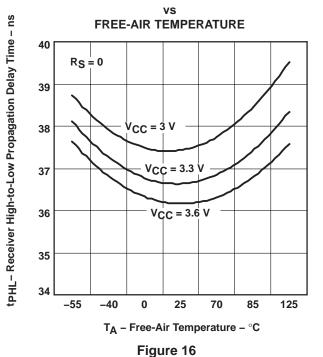




RECEIVER LOW-TO-HIGH PROPAGATION DELAY TIME



RECEIVER HIGH-TO-LOW PROPAGATION DELAY TIME



DRIVER LOW-TO-HIGH PROPAGATION DELAY TIME

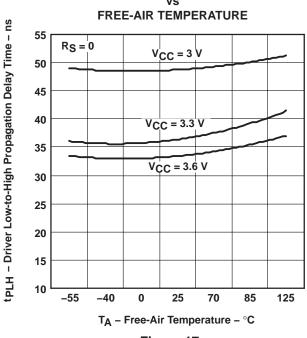


Figure 17

DRIVER HIGH-TO-LOW PROPAGATION DELAY TIME

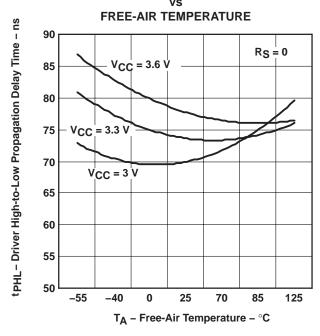
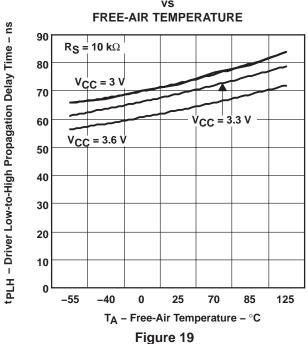
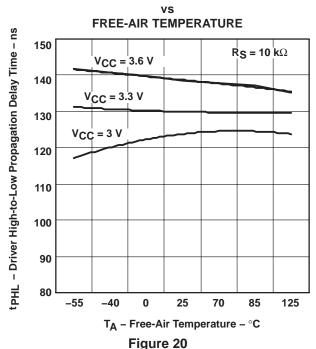


Figure 18

DRIVER LOW-TO-HIGH PROPAGATION DELAY TIME



DRIVER HIGH-TO-LOW PROPAGATION DELAY TIME



DRIVER LOW-TO-HIGH PROPAGATION DELAY TIME

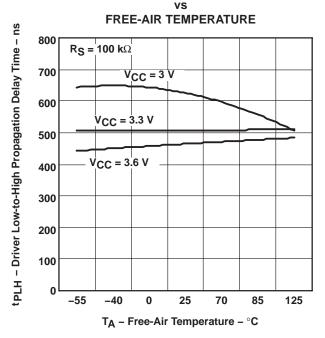


Figure 21

DRIVER OUTPUT CURRENT

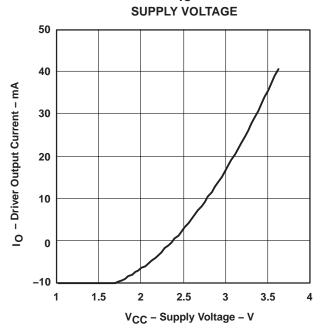


Figure 23

DRIVER HIGH-TO-LOW PROPAGATION DELAY TIME

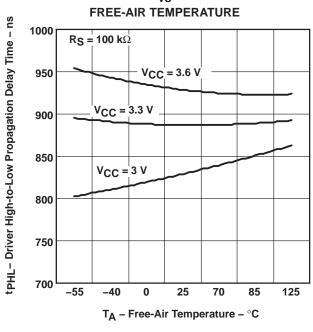


Figure 22

DIFFERENTIAL DRIVER OUTPUT FALL TIME vs Source Resistance (Rs)

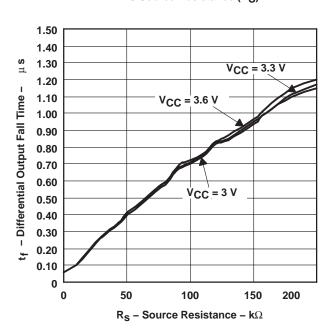


Figure 24



REFERENCE VOLTAGE vs REFERENCE CURRENT

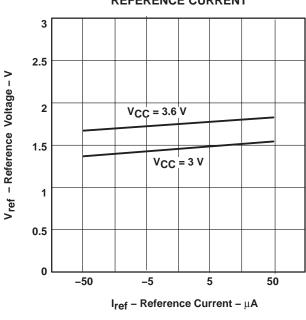


Figure 25

APPLICATION INFORMATION

This application provides information concerning the implementation of the physical medium attachment layer in a CAN network according to the ISO 11898 standard. It presents a typical application circuit and test results, as well as discussions on slope control, total loop delay, and interoperability in 5-V systems.

introduction

ISO 11898 is the international standard for high-speed serial communication using the controller area network (CAN) bus protocol. It supports multimaster operation, real-time control, programmable data rates up to 1 Mbps, and powerful redundant error checking procedures that provide reliable data transmission. It is suited for networking *intelligent* devices as well as sensors and actuators within the rugged electrical environment of a machine chassis or factory floor. The SN65HVD230M family of 3.3-V CAN transceivers implement the lowest layers of the ISO/OSI reference model. This is the interface with the physical signaling output of the CAN controller of the Texas Instruments TMS320Lx240x 3.3-V DSPs, as illustrated in Figure 26.



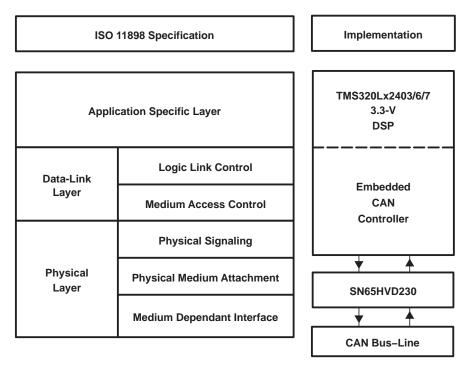


Figure 26. The Layered ISO 11898 Standard Architecture

The SN65HVD230M family of CAN transceivers are compatible with the ISO 11898 standard; this ensures interoperability with other standard-compliant products.

application of the SN65HVD230M

Figure 27 illustrates a typical application of the SN65HVD230M family. The output of a DSP's CAN controller is connected to the serial driver input, pin D, and receiver serial output, pin R, of the transceiver. The transceiver is then attached to the differential bus lines at pins CANH and CANL. Typically, the bus is a twisted pair of wires with a characteristic impedance of 120 Ω , in the standard half-duplex multipoint topology of Figure 28. Each end of the bus is terminated with 120- Ω resistors in compliance with the standard to minimize signal reflections on the bus.

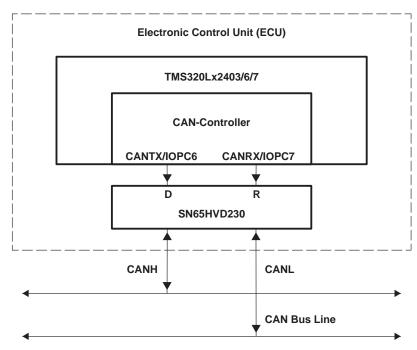


Figure 27. Details of a Typical CAN Node

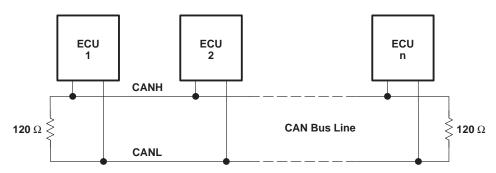


Figure 28. Typical CAN Network

The SN65HVD230M 3.3-V CAN transceivers provide the interface between the 3.3-V TMS320Lx2403/6/7 CAN DSPs and the differential bus line, and are designed to transmit data at signaling rates up to 1 Mbps as defined by the ISO 11898 standard.

features of the SN65HVD230M

These transceivers feature 3.3-V operation and standard compatibility with signaling rates up to 1 Mbps, and also offer 16-kV HBM ESD protection on the bus pins, thermal shutdown protection, bus fault protection, and open-circuit receiver failsafe. The failsafe design of the receiver assures a logic high at the receiver output if the bus wires become open circuited. If a high ambient operating environment temperature or excessive output current result in thermal shutdown, the bus pins become high impedance, while the D and R pins default to a logic high.



features of the SN65HVD230M (continued)

The bus pins are also maintained in a high-impedance state during low V_{CC} conditions to ensure glitch-free power-up and power-down bus protection for hot-plugging applications. This high-impedance condition also means that an unpowered node will not disturb the bus. Transceivers without this feature usually have a low output impedance. This results in a high current demand when the transceiver is unpowered, a condition that could affect the entire bus.

operating modes

R_S (pin 8) of the SN65HVD230M provides for three different modes of operation: high-speed mode, slope-control mode, and low-power standby mode.

high-speed mode

The high-speed mode can be selected by applying a logic low to Rs (pin 8). The high-speed mode of operation is commonly employed in industrial applications. High-speed allows the output to switch as fast as possible with no internal limitation on the output rise and fall slopes. The only limitations of the high-speed operation are cable length and radiated emission concerns, each of which is addressed by the slope control mode of operation.

If the low-power standby mode is to be employed in the circuit, direct connection to a DSP output pin can be used to switch between a logic-low level (< 1 V) for high speed mode operation, and the logic-high level ($> 0.75 \text{ V}_{CC}$) for standby mode operation. Figure 29 shows a typical DSP connection and Figure 30 shows the SN65HVD230M driver output signal in high-speed mode on the CAN bus.



Figure 29. R_S (Pin 8) Connection to a TMS320LF2406/07 for High-Speed or Standby Mode Operation



high-speed mode (continued)

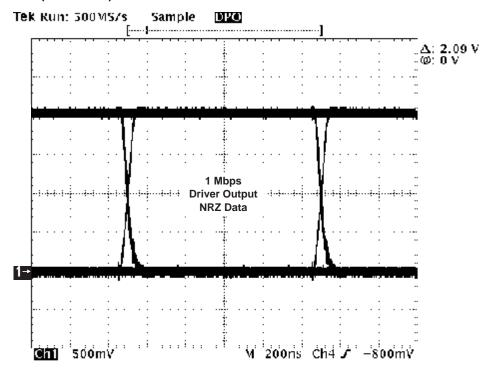


Figure 30. Typical SN65HVD230M High-Speed Mode Output Waveform Into a $60-\Omega$ Load

slope-control mode

Electromagnetic compatibility is essential in many applications using unshielded bus cable to reduce system cost. To reduce the electromagnetic interference generated by fast rise times and resulting harmonics, the rise and fall slopes of the SN65HVD230M driver outputs can be adjusted by connecting a resistor from R_S (pin 8) to ground or to a logic low voltage, as shown in Figure 31. The slope of the driver output signal is proportional to the pin's output current. This slope control is implemented with an external resistor value of 10 k Ω to achieve a \approx 15 V/ μ s slew rate, and up to 100 k Ω to achieve a \approx 2 V/ μ s slew rate as displayed in Figure 32. Typical driver output waveforms from a pulse input signal with and without slope control are displayed in Figure 33. A pulse input is used rather than NRZ data to clearly display the actual slew rate.

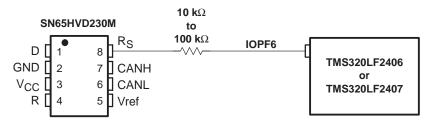


Figure 31. Slope-Control or Standby Mode Connection to a DSP





Figure 32. SN65HVD230M Driver Output Signal Slope vs Slope Control Resistance Value

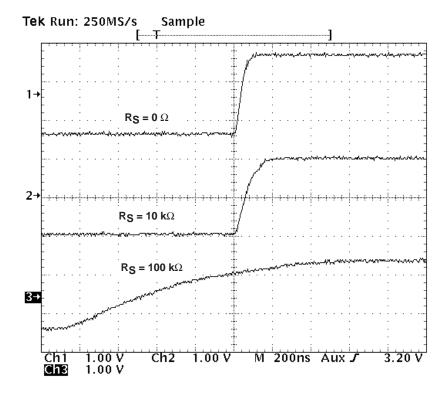


Figure 33. Typical SN65HVD230M 250-kbps Output Pulse Waveforms With Slope Control



standby mode (listen only mode) of the SN65HVD230M

If a logic high ($> 0.75 \text{ V}_{CC}$) is applied to R_S (pin 8) in Figure 29 and Figure 31, the circuit of the SN65HVD230M enters a low-current, *listen only* standby mode during which the driver is switched off and the receiver remains active. In this *listen only* state, the transceiver is completely passive to the bus. It makes no difference if a slope control resistor is in place as shown in Figure 31. The DSP can reverse this low-power standby mode when the rising edge of a dominant state (bus differential voltage > 900 mV typical) occurs on the bus. The DSP, sensing bus activity, reactivates the driver circuit by placing a logic low (< 1.2 V) on R_S (pin 8).

loop propagation delay

Transceiver loop delay is a measure of the overall device propagation delay, consisting of the delay from the driver input to the differential outputs, plus the delay from the receiver inputs to its output.

The loop delay of the transceiver displayed in Figure 34 increases accordingly when slope control is being used. This increased loop delay means that the total bus length must be reduced to meet the CAN bit-timing requirements of the overall system. The loop delay becomes $\approx\!100$ ns when employing slope control with a $10\text{-k}\Omega$ resistor, and $\approx\!500$ ns with a $100\text{-k}\Omega$ resistor. Therefore, considering that the rule-of-thumb propagation delay of typical bus cable is 5 ns/m, slope control with the $100\text{-k}\Omega$ resistor decreases the allowable bus length by the difference between the 500-ns max loop delay and the loop delay with no slope control, 70.7 ns. This equates to (500-70.7 ns)/5 ns, or approximately 86 m less bus length. This slew-rate/bus length trade-off to reduce electromagnetic interference to adjoining circuits from the bus can also be solved with a high-quality shielded bus cable.



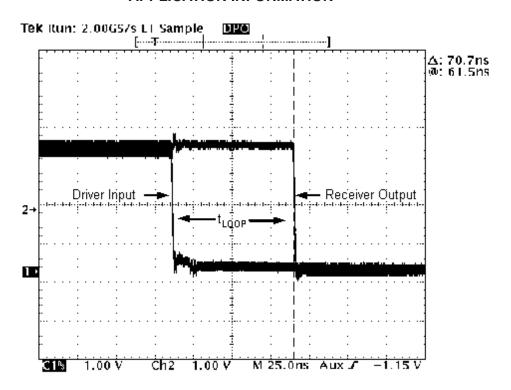


Figure 34. 70.7-ns Loop Delay Through the SN65HVD230M With $R_S = 0$



interoperability with 5-V CAN systems

It is essential that the 3.3-V SN65HVD230M family performs seamlessly with 5-V transceivers because of the large number of 5-V devices installed. Figure 35 displays a test bus of a 3.3-V node with the SN65HVD230M, and three 5-V nodes: one for each of Tl's SN65LBC031 and UC5350 transceivers, and one using a competitor X250 transceiver.

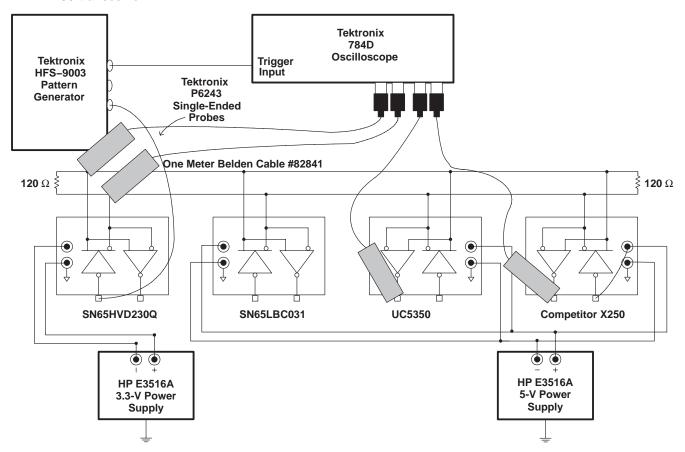


Figure 35. 3.3-V/5-V CAN Transceiver Test Bed



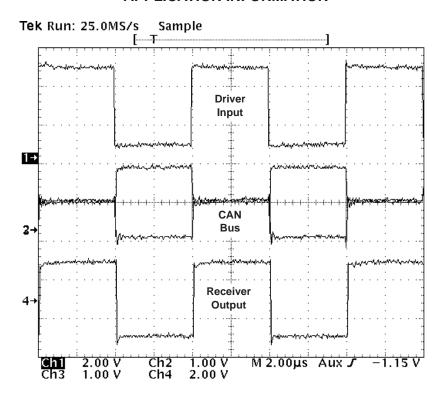


Figure 36. SN65HVD230M's Input, CAN Bus, and X250's RXD Output Waveforms

Figure 36 displays the SN65HVD230M's input signal, the CAN bus, and the competitor X250's receiver output waveforms. The input waveform from the Tektronix HFS-9003 Pattern Generator in Figure 35 to the SN65HVD230M is a 250-kbps pulse for this test. The circuit is monitored with Tektronix P6243, 1-GHz single-ended probes in order to display the CAN dominant and recessive bus states.

Figure 36 displays the 250-kbps pulse input waveform to the SN65HVD230M on channel 1. Channels 2 and 3 display CANH and CANL respectively, with their recessive bus states overlaying each other to clearly display the dominant and recessive CAN bus states. Channel 4 is the receiver output waveform of the competitor X250.



www.ti.com 11-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN65HVD230MDREP	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	H230EP
SN65HVD230MDREP.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	H230EP
V62/06629-01XE	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	H230EP

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

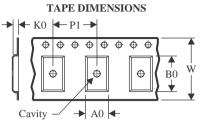
⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

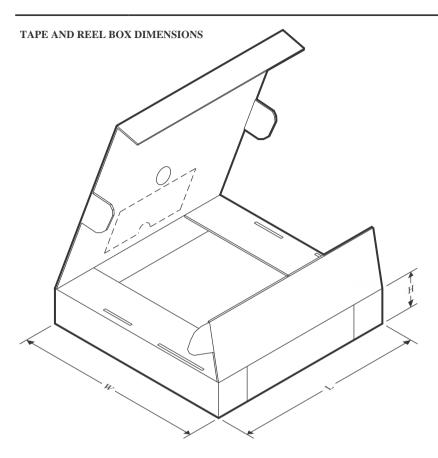
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65HVD230MDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

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*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
I	SN65HVD230MDREP	SOIC	D	8	2500	353.0	353.0	32.0



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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Last updated 10/2025